NSN 5962-01-339-5878

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-339-5878 **Body Length:** 1.285 inches **Body Width:** 0.600 inches **Body Height:** 0.187 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and w/enable and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Current Rating Per Characteristic:** 115.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.0 volts power source **Capitance Rating Per Characteristic:** 6.00 input picofarads and 12.00 output picofarads **Time Rating Per Chacteristic:** 450.00 nanoseconds delay **Memory Device Type: Eprom Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Unit Of Measure:

NSN 5962-01-339-5878

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0